



RECEIVED

JAN 02 2004

TC 1700

1756

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

TO: Commissioner for Patents
PO Box 1450
Alexandria, VA 22313-1450

FROM: Tung & Associates
838 West Long Lake Road - Suite 120
Bloomfield Hills, MI 48302

DATE: 29 November 2003

REF: Applicant : Hsieh et al. Filing Date : 11 October 2001
Serial No : 09/975,855 Att'y No. : 67,200-447
Art Unit : 1756 Examiner : Saleha R Mohamedulla
Title : Gap Forming Pattern Fracturing Method for Forming Optical
Proximity Corrected Masking Layer

RECEIVED

JAN 03 2004

TC 1700

AMENDMENT AND RESPONSE TO OFFICE ACTION

Sir:

In response to an office action mailed on 10 October 2003, please consider the following amendments and remarks pertaining to the above referenced application.

Amendments to the specification begin on page 2 of this paper. Amendments to the claims are found within a Listing of the Claims that begins on page 3 of this paper. Amendments to the drawings begin on page 7 of this paper. Remarks begin on page 8 of this paper.

BEST AVAILABLE COPY

CERTIFICATE OF MAILING

I hereby certify that this correspondence is being forwarded in an envelope with sufficient postage as first class mail to the Commissioner for Patents, POB 1450, Alexandria, VA 22313-1450 on Dec. 23, 2003.


Kathy Dixon